



#### 30V P-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub>	I <sub>D</sub> T <sub>C</sub> = +25°C
-30V	$25m\Omega$ @ $V_{GS} = -10V$	-27A
-307	38mΩ @ V <sub>GS</sub> = -4.5V	-22A

## **Description**

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## **Applications**

- Backlighting
- DC-DC Converters
- · Power Management Functions

### **Features**

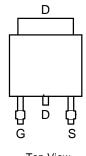
- 100% Unclamped Inductive Switch (UIS) Test In Production
- Low On-Resistance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Note 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

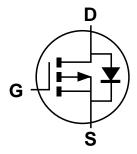
- Case: TO252
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208 (23)
- Weight: 0.33 grams (Approximate)



Top View



Top View Pin-Out



Equivalent Circuit

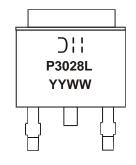
## **Ordering Information** (Notes 4)

_			
	Product	Case	Packaging
	DMP3028LK3-13	TO252	2,500/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html .

## **Marking Information**



D\| = Manufacturer's Marking
P3028L= Product Type Marking Code
YYWW = Date Code Marking
YY = Year (ex: 14 = 2014)
WW = Week (01 - 53)



# **Maximum Ratings** (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage	V <sub>DSS</sub>	-30	V		
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Steady $T_C = +25^{\circ}C$ State $T_C = +70^{\circ}C$		I <sub>D</sub>	-27 -22	А	
Continuous Drain Current (Note 6) V <sub>GS</sub> = -10V	t<10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	-11 -8.6	А
Maximum Body Diode Continuous Current			Is	-2.5	Α
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I <sub>DM</sub>	-40	А
Avalanche Current (Note 7) L = 0.1mH			las	-22	Α
Avalanche Energy (Note 7) L = 0.1mH			Eas	24	mJ

# Thermal Characteristics ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	D-	1.6	W
Total Power Dissipation (Note 5)	T <sub>A</sub> = +70°C	$P_{D}$	1.0	
Thermal Resistance, Junction to Ambient (Note 5)	Steady state	D	77	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{\theta JA}$	34	
Total Power Dissipation (Note 6)	$T_A = +25$ °C	D-	2.8	W
Total Fower Dissipation (Note o)	$T_A = +70^{\circ}C$	$P_{D}$	1.8	
Thermal Resistance, Junction to Ambient (Note 6)	Steady state	D	45	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{\theta JA}$	29	
Thermal Resistance, Junction to Case (Note 6)	$R_{ heta JC}$	4.5		
Operating and Storage Temperature Range		$T_{J_i}T_{STG}$	-55 to +150	°C

## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-30	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	I <sub>DSS</sub>	_	_	-1	μA	$V_{DS} = -30V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	-1	1	-2.4	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance	D		20	25	mΩ	$V_{GS} = -10V, I_D = -7A$	
Static Dialit-Source Off-Resistance	R <sub>DS(ON)</sub>	_	29	38	11122	$V_{GS} = -4.5V$ , $I_D = -6.2A$	
Diode Forward Voltage	V <sub>SD</sub>	_	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -2.1A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C <sub>iss</sub>	1	1241	_	pF	\	
Output Capacitance	Coss		147	_	pF	$V_{DS} = -15V, V_{GS} = 0V$ f = 1.0MHz $V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Reverse Transfer Capacitance	Crss	_	110	_	pF		
Gate Resistance	$R_{G}$	_	15	_	Ω		
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg	_	22	_	nC		
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg		11	_	nC	- Vps = -15V. ID = -7A	
Gate-Source Charge	Qgs	_	3.5	_	nC	VDS = -15V, ID = -7A	
Gate-Drain Charge	Q <sub>gd</sub>		4.7	_	nC		
Turn-On Delay Time	t <sub>D(on)</sub>		9.7	_	ns		
Turn-On Rise Time	tr		17.1	_	ns	$V_{GS} = -10V, V_{DD} = -15V,$	
Turn-Off Delay Time	t <sub>D(off)</sub>	_	60.5	_	ns	$R_{GEN} = 6\Omega$ $I_D = -7A$	
Turn-Off Fall Time	t <sub>f</sub>	_	40.4	_	ns		

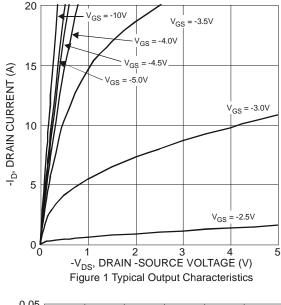
5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

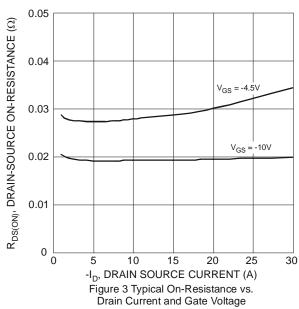
7.  $I_{AS}$  and  $E_{AS}$  rating are based on low frequency and duty cycles to keep  $T_J = 25^{\circ}C$ .

8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to product testing.







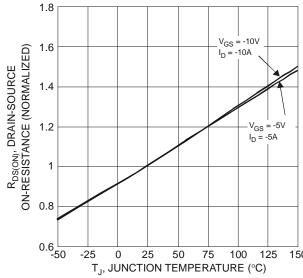
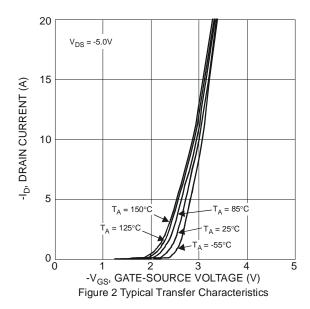
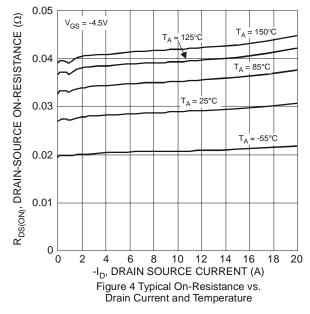
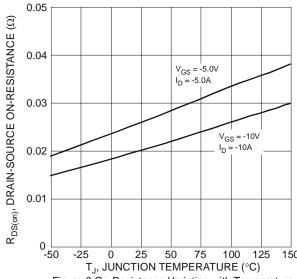


Figure 5 On-Resistance Variation with Temperature









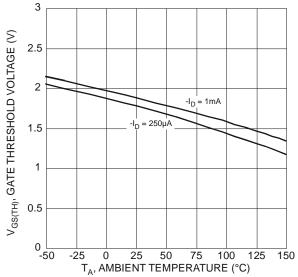


Figure 7 Gate Threshold Variation vs. Ambient Temperature

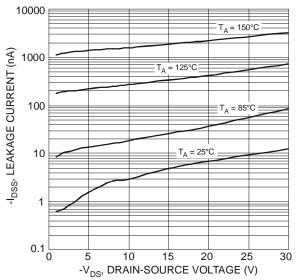
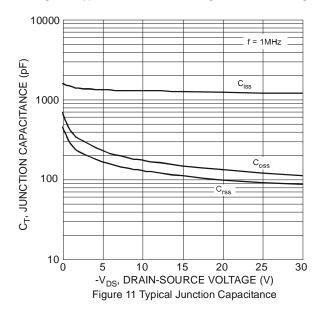
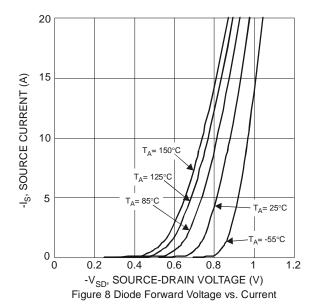
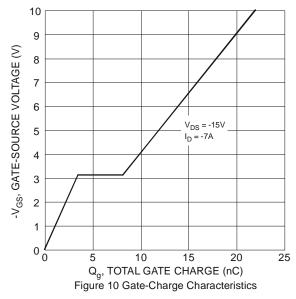


Figure 9 Typical Drain-Source Leakage Current vs. Voltage







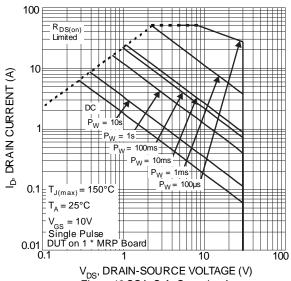
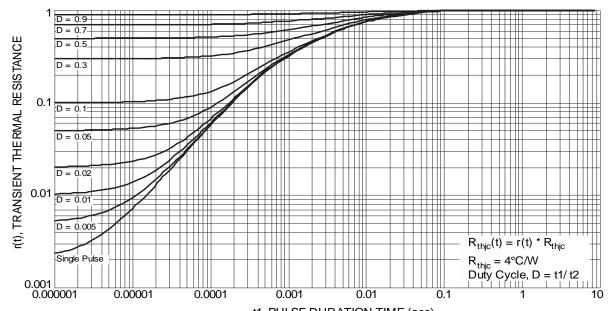


Figure 12 SOA, Safe Operation Area



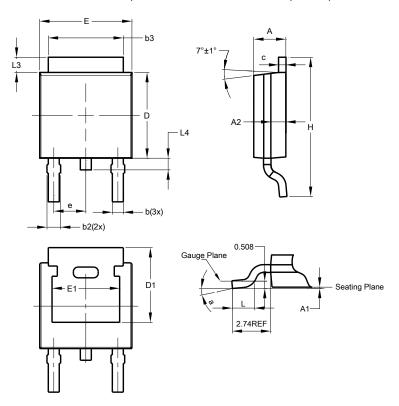


t1, PULSE DURATION TIME (sec) Figure 13 Transient Thermal Resistance



## **Package Outline Dimensions**

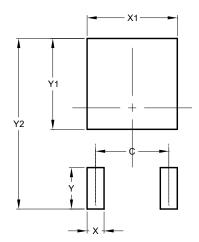
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
<b>A1</b>	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
С	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-	-		
е	-	-	2.286		
Е	6.45	6.70	6.58		
E1	4.32	-	-		
Н	9.40	10.41	9.91		
٦	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	-		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
С	4.572		
Х	1.060		
X1	5.632		
Υ	2.600		
Y1	5.700		
Y2	10.700		



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